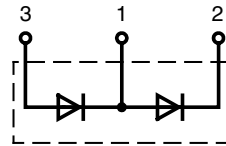


High Power Diode Modules

Preliminary data

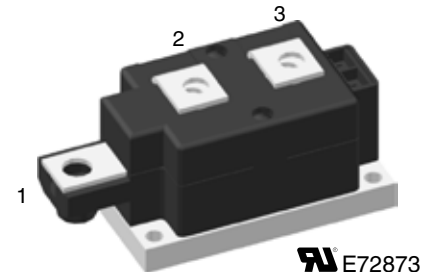
| V_{RSM} V | V_{RRM} V | Type |
|----------------|----------------|--------------|
| 2900 | 2800 | MDD 175-28N1 |
| 3500 | 3400 | MDD 175-34N1 |



$$I_{FRMS} = 2x 564 \text{ A}$$

$$I_{FAVM} = 2x 177 \text{ A}$$

$$V_{RRM} = 2800-3400 \text{ V}$$



| Symbol | Conditions | Maximum Ratings |
|------------|---|---|
| I_{FRMS} | $T_{VJ} = T_{VJM}$ | $T_C = 25^\circ\text{C}$ 564 A |
| I_{FAVM} | 180° sine | $T_C = 100^\circ\text{C}$ 177 A |
| I_{FSM} | $T_{VJ} = 45^\circ\text{C}; V_R = 0$ | $t = 10 \text{ ms}$ (50 Hz) 4500 A |
| | | $t = 8.3 \text{ ms}$ (60 Hz) 4800 A |
| | $T_{VJ} = T_{VJM}; V_R = 0$ | $t = 10 \text{ ms}$ (50 Hz) 3900 A |
| | | $t = 8.3 \text{ ms}$ (60 Hz) 4200 A |
| I^2t | $T_{VJ} = 45^\circ\text{C}; V_R = 0$ | $t = 10 \text{ ms}$ (50 Hz) 101250 A ² s |
| | | $t = 8.3 \text{ ms}$ (60 Hz) 97000 A ² s |
| | $T_{VJ} = T_{VJM}; V_R = 0$ | $t = 10 \text{ ms}$ (50 Hz) 76000 A ² s |
| | | $t = 8.3 \text{ ms}$ (60 Hz) 74000 A ² s |
| T_{VJ} | | -40...+140 °C |
| T_{VJM} | | 140 °C |
| T_{stg} | | -40...+125 °C |
| V_{ISOL} | 50/60 Hz, RMS $t = 1 \text{ min}$ $I_{ISOL} \leq 1 \text{ mA}$ $t = 1 \text{ s}$ | 3000 V~ |
| | | 3600 V~ |
| M_d | Mounting torque (M6) | 4.5 - 7 Nm |
| | Terminal connection torque (M8) | 11-13 Nm |
| Weight | Typical including screws | 750 g |

Features

- International standard package
- Direct Copper Bonded Al_2O_3 ceramic with copper base plate
- Planar passivated chips
- Isolation voltage 3600 V~
- UL registered

Applications

- Supplies for DC power equipment
- DC supply for PWM inverter
- Field supply for DC motors
- Battery DC power supplies

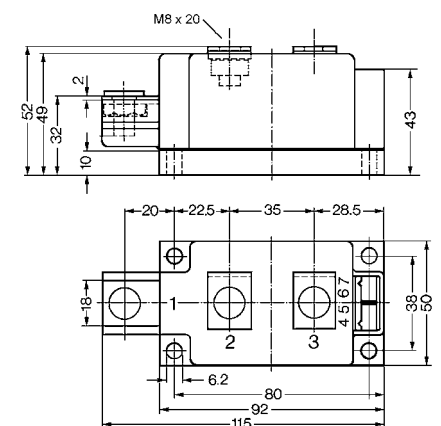
Advantages

- Simple mounting
- Improved temperature & power cycling
- Reduced protection circuits

| Symbol | Conditions | Characteristics Values |
|------------|--|------------------------|
| I_{RRM} | $V_R = V_{RRM}$ $T_{VJ} = T_{VJM}$ | 5 mA |
| V_F | $I_F = 300 \text{ A}; T_{VJ} = 25^\circ\text{C}$ | 1.25 V |
| V_{T0} | For power-loss calculations only | 0.9 V |
| r_t | $T_{VJ} = T_{VJM}$ | 1.4 mΩ |
| R_{thJC} | per diode; DC current | 0.14 K/W |
| | per module | 0.07 K/W |
| R_{thJK} | per diode; DC current | 0.18 K/W |
| | per module | 0.09 K/W |
| Q_S | $I_F = 400 \text{ A}; -di/dt = 50 \text{ A}/\mu\text{s}; T_{VJ} = 125^\circ\text{C}$ | tbd μC |
| I_{RM} | | tbd A |
| d_s | Creeping distance on surface | 12.7 mm |
| d_A | Creepage distance in air | 9.6 mm |
| a | Maximum allowable acceleration | 50 m/s ² |

Data according to IEC 60747 and refer to a single diode unless otherwise stated.

Dimensions in mm (1 mm = 0.0394")



Optional accessories for modules
 Keyed Gate/Cathode twin plugs with wire length = 350 mm, gate = yellow, cathode = red
 Type ZY 180 L (L = Left for pin pair 4/5) } UL 758, style 1385.
 Type ZY 180 R (R = Right for pin pair 6/7) } CSA class 5851, guide 460-1-1

IXYS reserves the right to change limits, test conditions and dimensions.

20091110d

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